



Integrated  
Circuit  
Systems, Inc.

## ICS8302

### LOW SKEW, 1-TO-2 LVC MOS / LVTTL FANOUT BUFFER

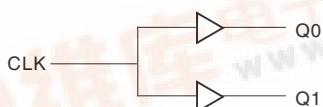
## GENERAL DESCRIPTION

 The ICS8302 is a low skew, 1-to-2 LVC MOS Fanout Buffer and a member of the HiPerClock<sup>S</sup>™ family of High Performance Clock Solutions from ICS. The ICS8302 has a single ended clock input. The single ended clock input accepts LVC MOS or LVTTL input levels. The ICS8302 features a pair of LVC MOS/LVTTL outputs. The ICS8302 is characterized at full 3.3V for input V<sub>DD</sub>, and mixed 3.3V and 2.5V for output operating supply modes (V<sub>DDO</sub>). Guaranteed output and part-to-part skew characteristics make the ICS8302 ideal for clock distribution applications demanding well defined performance and repeatability.

## FEATURES

- 2 LVC MOS / LVTTL outputs
- LVC MOS / LVTTL clock input accepts LVC MOS or LVTTL input levels
- Maximum output frequency: 200MHz
- Output skew: 25ps (typical)
- Part-to-part skew: 250ps (typical)
- Small 8 lead SOIC package saves board space
- Full 3.3V or 3.3V core, 2.5V supply modes
- 0°C to 70°C ambient operating temperature
- Lead-Free package available
- Industrial temperature information available upon request

## BLOCK DIAGRAM



## PIN ASSIGNMENT

V <sub>DDO</sub>	1	8	Q0
V <sub>DD</sub>	2	7	GND
CLK	3	6	V <sub>DDO</sub>
GND	4	5	Q1

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#### 8-Lead SOIC

3.8mm x 4.8mm, x 1.47mm package body

#### M Package

Top View



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**TABLE 1. PIN DESCRIPTIONS**

Number	Name	Type	Description
1, 6	$V_{DDO}$	Power	Output supply pins.
2	$V_{DD}$	Power	Core supply pin.
3	CLK	Input	Pulldown
4,7	GND	Power	Power supply ground.
5	Q1	Output	Single clock output. LVC MOS / LVTTL interface levels.
8	Q0	Output	Single clock output. LVC MOS / LVTTL interface levels.

NOTE: *Pullup* and *Pulldown* refer to internal input resistors. See Table 2, Pin Characteristics, for typical values.

**TABLE 2. PIN CHARACTERISTICS**

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$C_{IN}$	Input Capacitance			4		pF
$C_{PD}$	Power Dissipation Capacitance (per output)	$V_{DD}, V_{DDO} = 3.465V$		22		pF
		$V_{DD} = 3.465V, V_{DDO} = 2.625V$		16		pF
$R_{PULLDOWN}$	Input Pulldown Resistor			51		KΩ
$R_{OUT}$	Output Impedance		5	7	12	Ω



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### ABSOLUTE MAXIMUM RATINGS

Supply Voltage, $V_{DD}$	4.6V
Inputs, $V_I$	-0.5V to $V_{DD} + 0.5$ V
Outputs, $V_O$	-0.5V to $V_{DD} + 0.5$ V
Package Thermal Impedance, $\theta_{JA}$	112.7°C/W (0 lfpm)
Storage Temperature, $T_{STG}$	-65°C to 150°C

NOTE: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

TABLE 3A. POWER SUPPLY DC CHARACTERISTICS,  $V_{DD} = V_{DDO} = 3.3V \pm 5\%$ ,  $T_A = 0^\circ C$  TO  $70^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$V_{DD}$	Core Supply Voltage		3.135	3.3	3.465	V
$V_{DDO}$	Output Power Supply Voltage		3.135	3.3	3.465	V
$I_{DD}$	Power Supply Current				13	mA
$I_{DDO}$	Output Supply Current				4	mA

TABLE 3B. LVC MOS / LVTTL DC CHARACTERISTICS,  $V_{DD} = V_{DDO} = 3.3V \pm 5\%$ ,  $T_A = 0^\circ C$  TO  $70^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$V_{IH}$	Input High Voltage		2		$V_{DD} + 0.3$	V
$V_{IL}$	Input Low Voltage		-0.3		1.3	V
$I_{IH}$	Input High Current	CLK	$V_{DD} = V_{IN} = 3.465V$		150	$\mu A$
$I_{IL}$	Input Low Current	CLK	$V_{DD} = 3.465V$ , $V_{IN} = 0V$	-5		$\mu A$
$V_{OH}$	Output High Voltage		50 $\Omega$ to $V_{DDO}/2$	2.6		V
			$I_{OH} = -100\mu A$	2.9		V
$V_{OL}$	Output Low Voltage		50 $\Omega$ to $V_{DDO}/2$		0.5	V
			$I_{OL} = 100\mu A$		0.2	V

TABLE 4A. AC CHARACTERISTICS,  $V_{DD} = V_{DDO} = 3.3V \pm 5\%$ ,  $T_A = 0^\circ C$  TO  $70^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$f_{MAX}$	Output Frequency				200	MHz
$tp_{LH}$	Propagation Delay, Low-to-High; NOTE 1	$f \leq 200$ MHz	1.9	2.35	2.8	ns
$tsk(o)$	Output Skew; NOTE 2, 4			25	85	ps
$tsk(pp)$	Part-to-Part Skew; NOTE 3, 4			250	800	ps
$t_R$	Output Rise Time	20% to 80%	300		800	ps
$t_F$	Output Fall Time	20% to 80%	300		800	ps
odc	Output Duty Cycle	$f \leq 133$ MHz	45		55	%
		$133$ MHz < $f \leq 200$ MHz	40		60	%

Parameters measured at  $f_{MAX}$  unless otherwise noted.

NOTE 1: Measured from  $V_{DD}/2$  of the input to  $V_{DDO}/2$  of the output.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at  $V_{DDO}/2$ .

NOTE 3: Defined as skew between outputs on different devices operating at the same supply voltages and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at  $V_{DDO}/2$ .

NOTE 4: This parameter is defined in accordance with JEDEC Standard 65.



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**TABLE 3C. POWER SUPPLY DC CHARACTERISTICS,  $V_{DD} = 3.3V \pm 5\%$ ,  $V_{DDO} = 2.5V \pm 5\%$ ,  $T_A = 0^\circ C$  TO  $70^\circ C$**

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$V_{DD}$	Core Supply Voltage		3.135	3.3	3.465	V
$V_{DDO}$	Output Supply Voltage		2.375	2.5	2.625	V
$I_{DD}$	Power Supply Current				13	mA
$I_{DDO}$	Output Supply Current				4	mA

**TABLE 3D. LVC MOS / LV TTL DC CHARACTERISTICS,  $V_{DD} = 3.3V \pm 5\%$ ,  $V_{DDO} = 2.5V \pm 5\%$ ,  $T_A = 0^\circ C$  TO  $70^\circ C$**

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$V_{IH}$	Input High Voltage		2		$V_{DD} + 0.3$	V
$V_{IL}$	Input Low Voltage		-0.3		1.3	V
$I_{IH}$	Input High Current	CLK	$V_{DD} = V_{IN} = 3.465V$		150	$\mu A$
$I_{IL}$	Input Low Current	CLK	$V_{DD} = 3.465V$ , $V_{IN} = 0V$	-5		$\mu A$
$V_{OH}$	Output High Voltage		50 $\Omega$ to $V_{DDO}/2$	1.8		V
			$I_{OH} = -100\mu A$	2.2		V
$V_{OL}$	Output Low Voltage		50 $\Omega$ to $V_{DDO}/2$		0.5	V
			$I_{OL} = 100\mu A$		0.2	V

**TABLE 4B. AC CHARACTERISTICS,  $V_{DD} = 3.3V \pm 5\%$ ,  $V_{DDO} = 2.5V \pm 5\%$ ,  $T_A = 0^\circ C$  TO  $70^\circ C$**

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$f_{MAX}$	Output Frequency				200	MHz
$tp_{LH}$	Propagation Delay, Low-to-High; NOTE 1	$f \leq 200MHz$	2.3		3.3	ns
$tsk(o)$	Output Skew; NOTE 2, 4				85	ps
$tsk(pp)$	Part-to-Part Skew; NOTE 3, 4			250	800	ps
$t_R$	Output Rise Time	20% to 80%	250		650	ps
$t_F$	Output Fall Time	20% to 80%	250		650	ps
odc	Output Duty Cycle	$f \leq 133MHz$	45		55	%
		$133MHz < f \leq 200MHz$	40		60	%

Parameters measured at  $f_{MAX}$  unless otherwise noted.

NOTE 1: Measured from  $V_{DD}/2$  of the input to  $V_{DDO}/2$  of the output.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions.

Measured at  $V_{DDO}/2$ .

NOTE 3: Defined as skew between outputs on different devices operating at the same supply voltages and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at  $V_{DDO}/2$ .

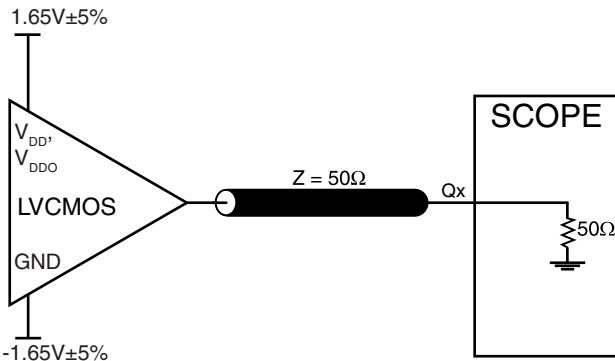
NOTE 4: This parameter is defined in accordance with JEDEC Standard 65.



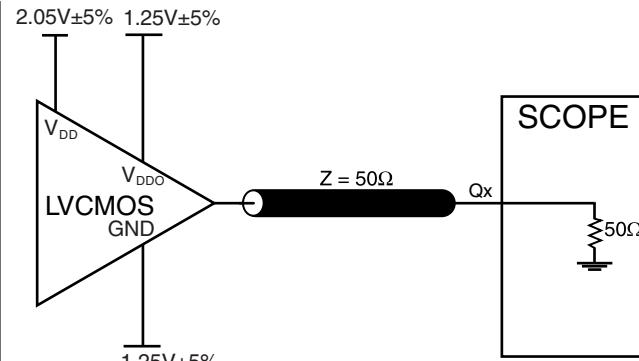
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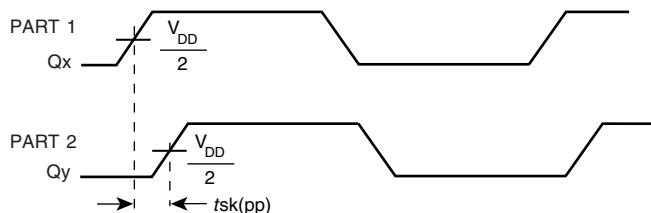
## PARAMETER MEASUREMENT INFORMATION



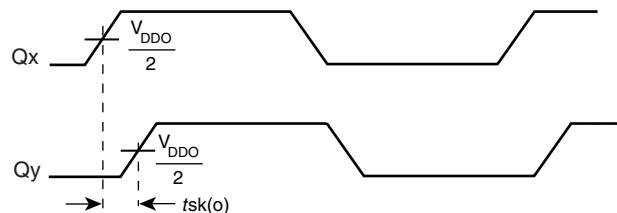
**3.3V OUTPUT LOAD AC TEST CIRCUIT**



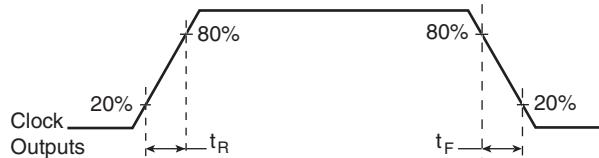
**3.3V/2.5V OUTPUT LOAD AC TEST CIRCUIT**



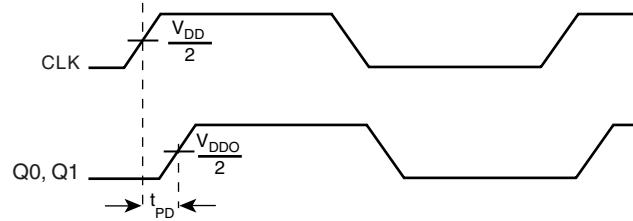
**PART-TO-PART SKEW**



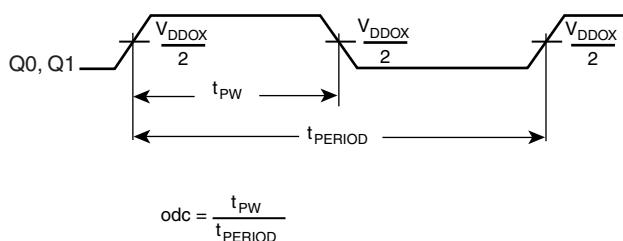
**OUTPUT SKEW**



**OUTPUT RISE/FALL TIME**



**PROPAGATION DELAY**



**OUTPUT PULSE WIDTH/PERIOD**



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## RELIABILITY INFORMATION

TABLE 5.  $\theta_{JA}$  vs. AIR FLOW TABLE FOR 8 LEAD SOIC

### $\theta_{JA}$ by Velocity (Linear Feet per Minute)

	0	200	500
Single-Layer PCB, JEDEC Standard Test Boards	153.3°C/W	128.5°C/W	115.5°C/W
Multi-Layer PCB, JEDEC Standard Test Boards	112.7°C/W	103.3°C/W	97.1°C/W

**NOTE:** Most modern PCB designs use multi-layered boards. The data in the second row pertains to most designs.

### TRANSISTOR COUNT

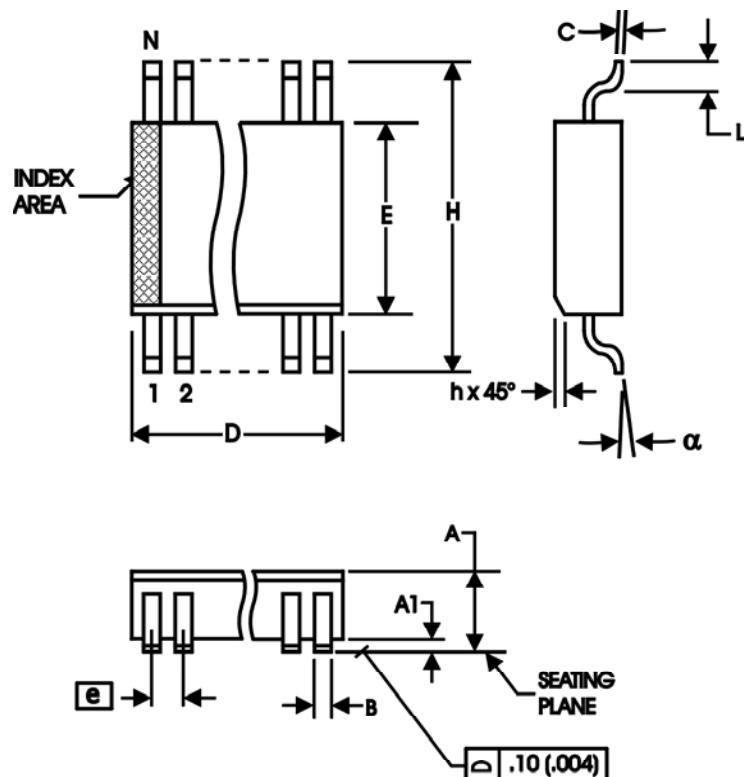
The transistor count for ICS8302 is: 322



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**PACKAGE OUTLINE - SUFFIX M FOR 8 LEAD SOIC**



**TABLE 6. PACKAGE DIMENSIONS**

SYMBOL	Millimeters	
	MINIMUM	MAXIMUM
N		8
A	1.35	1.75
A1	0.10	0.25
B	0.33	0.51
C	0.19	0.25
D	4.80	5.00
E	3.80	4.00
e	1.27 BASIC	
H	5.80	6.20
h	0.25	0.50
L	0.40	1.27
alpha	0°	8°

Reference Document: JEDEC Publication 95, MS-012



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**TABLE 7. ORDERING INFORMATION**

Part/Order Number	Marking	Package	Count	Temperature
ICS8302AM	8302AM	8 lead SOIC	96 per tube	0°C to 70°C
ICS8302AMT	8302AM	8 lead SOIC on Tape and Reel	2500	0°C to 70°C
ICS8302AMLF	8302AMLF	8 lead "Lead Free" SOIC	96 per tube	0°C to 70°C
ICS8302AMLFT	8302AMLF	8 lead "Lead Free" SOIC on Tape and Reel	2500	0°C to 70°C

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REVISION HISTORY SHEET				
Rev	Table	Page	Description of Change	Date
B	T1	2	Pin Description table, revised $V_{DD}$ description.	
	T2	2	Pin Characteristics table, deleted $R_{PULLUP}$ row.	
	T3A & T3C	3, 4	Power Supply table, changed $V_{DD}$ parameter to correspond with description.	2/4/03
	T4A & T4B	3, 4	AC Characteristics tables - added note "Parameters measured at $f_{MAX}$ unless otherwise noted." $tp_{LH}$ Test Conditions, added $f \leq 200\text{MHz}$ .	
C	T2	2	Pin Characteristics table - changed $C_{IN}$ 4pF max. to 4pF typical. Added 5Ω min. and 12Ω max. to $R_{OUT}$ row.	6/15/04
	T7	8	Ordering Information table - added "Lead-Free" part number.	